

Switchmode Dual Ultrafast Power Rectifiers

- -- Designed for use in switching power supplies inverters and as free wheeling diodes. These state-of-the-art devices have the following features:
 - * High Surge Capacity
 - *Low Power Loss, High efficiency
 - * Glass Passivated chip junctions
 - * 150 °C Operating Junction Temperature
 - * Low Stored Charge Majority Carrier Conduction
 - *Low Forward Voltage, High Current Capability
 - * High-Switching Speed 35 Nanosecong Recovery Time
 - * Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O

Plating pb free is indicated by box



MAXIMUM RATINGS

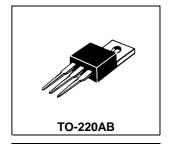
Characteristic	Symbol	U12C05	U12C10	U12C15	U12C20	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	50	100	150	200	٧
RMS Reverse Voltage	V _{R(RMS)}	35	70	105	140	V
Average Rectifier Forward Current Total Device (Rated V _R), T _C =100	I _{F(AV)}	6.0 12			Α	
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz)	I _{FM}	12			Α	
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I _{FSM}	100			Α	
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150				

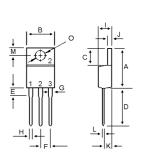
ELECTRIAL CHARACTERISTICS

LEECTRIAL CHARACTERISTICS						
Characteristic	Symbol	U10C05	U10C10	U10C15	U10C20	Unit
Maximum Instantaneous Forward Voltage ($I_F = 6.0 \text{ Amp } T_C = 25$) ($I_F = 6.0 \text{ Amp } T_C = 125$)	V _F	0.975 0.880			٧	
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25$) (Rated DC Voltage, $T_C = 125$)	I _R	5.0 200			uA	
Reverse Recovery Time ($I_F = 0.5 \text{ A}$, $I_R = 1.0$, $I_{rr} = 0.25 \text{ A}$)	T _{rr}	35			ns	
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	C _P	55		₽F		

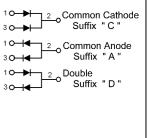
ULTRA FAST RECTIFIERS

12 AMPERES 50-200 VOLTS



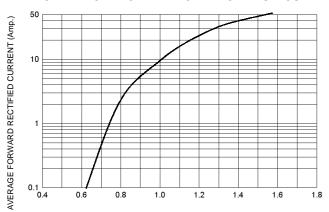


DIM	MILLIMETERS			
DIIVI	MIN	MAX		
Α	14.68	15.32		
В	9.78	10.42		
С	6.02	6.52		
D	13.06	14.62		
E	3.57	4.07		
F	2.42	2.66		
G	1.12	1.36		
Н	0.72	0.96		
- 1	4.22	4.98		
J	1.14	1.38		
K	2.20	2.98		
L	0.33	0.55		
M	2.48	2.98		
0	3.70	3.90		



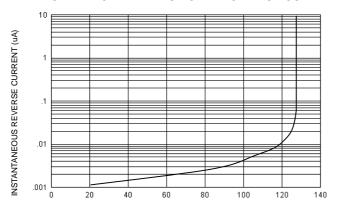
U12C05 Thru U12C20

FIG-1 TYPICAL FORWARD CHARACTERISITICS

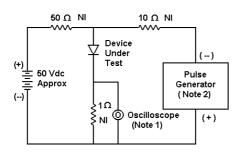


FORWARD VOLTAGE (Volts)

FIG-2 TYPICAL REVERSE CHARACTERISTICS



PERCENT OF PEAK REVERSE VOLTAGE (%)



- Notes: 1. Rise Time = 7 ns max. Input Impedance =1 M Ω , 22 pF
- 2. Rise Time = 10 ns max. Input Impedance = 50 Ω

FIG-3 FORWARD CURRENT DERATING CURVE

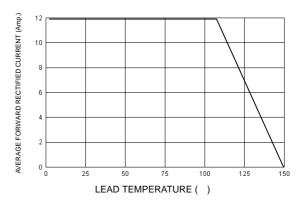


FIG-4TYPICAL JUNCTION CAPACITANCE

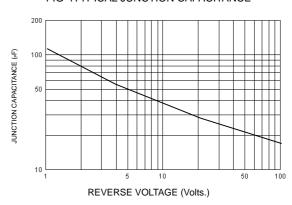
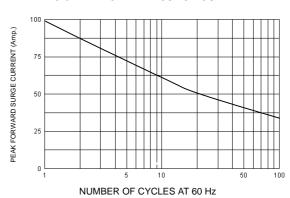
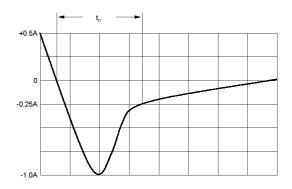


FIG-5PEAK FORWARD SURGE CURRENT





Set time base for 10/20 ns/cm

FIG-6 Reverse Recovery Time Characteristic and Test Circuit Diagram



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